Single Supply Dual Operational Amplifiers

Utilizing the circuit designs perfected for Quad Operational Amplifiers, these dual operational amplifiers feature low power drain, a common mode input voltage range extending to ground/ $V_{\rm EE}$, and single supply or split supply operation. The LM358 series is equivalent to one–half of an LM324.

These amplifiers have several distinct advantages over standard operational amplifier types in single supply applications. They can operate at supply voltages as low as 3.0 V or as high as 32 V, with quiescent currents about one–fifth of those associated with the MC1741 (on a per amplifier basis). The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications. The output voltage range also includes the negative power supply voltage.

Features

- Short Circuit Protected Outputs
- True Differential Input Stage
- Single Supply Operation: 3.0 V to 32 V
- Low Input Bias Currents
- Internally Compensated
- Common Mode Range Extends to Negative Supply
- Single and Split Supply Operation
- ESD Clamps on the Inputs Increase Ruggedness of the Device without Affecting Operation
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



ON Semiconductor®

www.onsemi.com



PDIP-8 N, AN, VN SUFFIX CASE 626

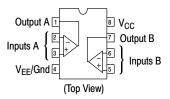


SOIC-8 D, VD SUFFIX CASE 751



Micro8™ DMR2 SUFFIX CASE 846A

PIN CONNECTIONS

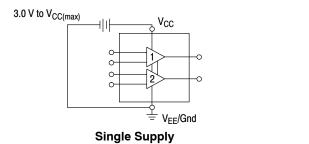


ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 11 of this data sheet.



V_{CC} 1.5 V to V_{CC(max)}

V_{EE} 1.5 V to V_{EE(max)}

Split Supplies

Figure 1.

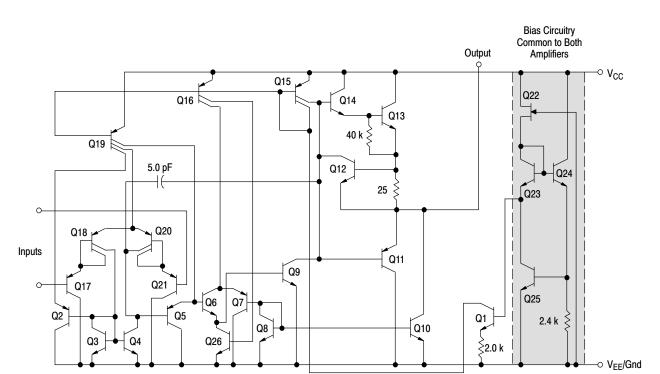


Figure 2. Representative Schematic Diagram (One-Half of Circuit Shown)

MAXIMUM RATINGS ($T_A = +25^{\circ}C$, unless otherwise noted.)

Rating	Symbol	Value	Unit
Power Supply Voltages Single Supply Split Supplies	V _{CC} V _{CC} , V _{EE}	32 ±16	Vdc
Input Differential Voltage Range (Note 1)	V _{IDR}	±32	Vdc
Input Common Mode Voltage Range	V _{ICR}	-0.3 to 32	Vdc
Output Short Circuit Duration	t _{SC}	Continuous	
Junction Temperature	T _J	150	°C
Thermal Resistance, Junction-to-Air (Note 2) Case 8 Case 8 Case 8	751	238 212 161	°C/W
Storage Temperature Range	T _{stg}	-65 to +150	°C
Operating Ambient Temperature Range LM LM358, LM358A, LM3 LM2904, LM2904A, LM29 LM2904V, NCV2904 (No	04E	-25 to +85 0 to +70 -40 to +105 -40 to +125	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ESD RATINGS

Rating	нвм	ММ	Unit
ESD Protection at any Pin (Human Body Model – HBM, Machine Model – MM)			
NCV2904 (Note 3)	2000	200	V
LM358E, LM2904E	2000	200	V
LM358DG/DR2G, LM2904DG/DR2G	250	100	V
All Other Devices	2000	200	V

^{1.} Split Power Supplies.

All R_{θ,JA} measurements made on evaluation board with 1 oz. copper traces of minimum pad size. All device outputs were active.
 NCV2904 is qualified for automotive use.

ELECTRICAL CHARACTERISTICS ($V_{CC} = 5.0 \text{ V}$, $V_{EE} = GND$, $T_A = 25^{\circ}C$, unless otherwise noted.)

ELECTRICAL CHARACTERISTICS (V _{CC} = 8	<u> </u>		LM258			58, LM			_M358A	\	
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage V_{CC} = 5.0 V to 30 V, V_{IC} = 0 V to V_{CC} -1.7 V, V_{O} = 1.4 V, R_{S} = 0 Ω	V _{IO}										mV
$T_A = 25^{\circ}C$		-	2.0	5.0	-	2.0	7.0	-	2.0	3.0	
$T_A = T_{high} \text{ (Note 4)}$		-	-	7.0	-	-	9.0	_	_	5.0	
$T_A = T_{low}$ (Note 4)		_	_	7.0	-	_	9.0	-	-	5.0	
Average Temperature Coefficient of Input Offset Voltage $T_A = T_{high}$ to T_{low} (Note 4)	$\Delta V_{IO}/\Delta T$	-	7.0	_	-	7.0	_	_	7.0	_	μV/°C
			0.0	00		5.0			5.0	00	- 1
Input Offset Current $T_A = T_{high}$ to T_{low} (Note 4)	I _{IO}	_	3.0	30 100	_	5.0 –	50 150	_	5.0	30 75	nA
Input Bias Current	I _{IB}	_	-45	-150	_	-45	-250	_	-45	-100	
$T_A = T_{high}$ to T_{low} (Note 4)	-10	_	-50	-300	_	-50	-500	_	-50	-200	
Average Temperature Coefficient of Input Offset Current $T_{A} = T_{high} \text{ to } T_{low} \text{ (Note 4)}$	$\Delta I_{IO}/\Delta T$	_	10	_	-	10	_	_	10	_	pA/°C
Input Common Mode Voltage Range (Note 5), V _{CC} = 30 V	V _{ICR}	0	_	28.3	0	_	28.3	0	_	28.5	V
$V_{CC} = 30 \text{ V}, T_A = T_{high} \text{ to } T_{low}$		0	_	28	0	_	28	0	_	28	
Differential Input Voltage Range	V _{IDR}	_	_	V _{CC}	_	_	V _{CC}	_	_	V _{CC}	V
Large Signal Open Loop Voltage Gain				- 00			- 00			00	V/mV
$R_L = 2.0 \text{ k}\Omega$, $V_{CC} = 15 \text{ V}$, For Large V_O Swing,	A _{VOL}	50	100	_	25	100	_	25	100	_	V/IIIV
$T_A = T_{high}$ to T_{low} (Note 4)		25	-	_	15	-	_	15	-	_	
Channel Separation 1.0 kHz ≤ f ≤ 20 kHz, Input Referenced	CS	-	-120	-	-	-120	-	_	-120	_	dB
Common Mode Rejection $R_S \le 10 \text{ k}\Omega$	CMR	70	85	-	65	70	-	65	70	-	dB
Power Supply Rejection	PSR	65	100	-	65	100	-	65	100	-	dB
Output Voltage-High Limit TA = T _{high} to T _{low} (Note 4)	V _{OH}										V
V_{CC} = 5.0 V, R_L = 2.0 kΩ, T_A = 25°C V_{CC} = 30 V, R_L = 2.0 kΩ		3.3 26	3.5	_	3.3 26	3.5	_	3.3 26	3.5	_	
$V_{CC} = 30 \text{ V}, R_{L} = 2.0 \text{ k}\Omega$ $V_{CC} = 30 \text{ V}, R_{L} = 10 \text{ k}\Omega$		27	28	_	27	28	_	27	28	_	
Output Voltage–Low Limit V_{CC} = 5.0 V, R_L = 10 k Ω , T_A = T_{high} to T_{low} (Note 4)	V _{OL}	-	5.0	20	-	5.0	20	_	5.0	20	mV
Output Source Current $V_{ID} = +1.0 \text{ V, } V_{CC} = 15 \text{ V}$ $T_A = T_{high} \text{ to } T_{low} \text{ (LM358A Only)}$	I _{O +}	20	40	-	20	40	-	20 10	40 -	- -	mA
Output Sink Current $V_{ID} = -1.0 \text{ V, } V_{CC} = 15 \text{ V}$ $T_A = T_{high} \text{ to } T_{low} \text{ (LM358A Only)}$	I _{O -}	10	20	-	10	20	-	10 5.0	20	- -	mA mA
$V_{ID} = -1.0 \text{ V}, V_{O} = 200 \text{ mV}$		12	50	-	12	50	-	12	50	-	μΑ
Output Short Circuit to Ground (Note 6)	I _{SC}	_	40	60	-	40	60	-	40	60	mA
Power Supply Current (Total Device) $T_{A} = T_{high} \text{ to } T_{low} \text{ (Note 4)}$	I _{CC}									0.0	mA
$V_{CC} = 30 \text{ V}, V_{O} = 0 \text{ V}, R_{L} = \infty$ $V_{CC} = 5 \text{ V}, V_{O} = 0 \text{ V}, R_{L} = \infty$		- -	1.5 0.7	3.0 1.2	- - 250E: T	1.5 0.7	3.0 1.2	- - - \70°	1.5 0.7	2.0 1.2	

^{4.} LM258: T_{low} = -25°C, T_{high} = +85°C LM2904/A/E: T_{low} = -40°C, T_{high} = +105°C NCV2904 is qualified for automotive use.

LM358, LM358A, LM358E: T_{low} = 0°C, T_{high} = +70°C LM2904V & NCV2904: T_{low} = -40°C, T_{high} = +125°C

The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common mode voltage range is V_{CC} – 1.7 V.
 Short circuits from the output to V_{CC} can cause excessive heating and eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.

 $\textbf{ELECTRICAL CHARACTERISTICS} \; (V_{CC} = 5.0 \; V, \, V_{EE} = Gnd, \, T_A = 25^{\circ}C, \, unless \; otherwise \; noted.)$

$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	50 200 -250 -500	Unit mV μV/°C nA pA/°C
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	13 10 - ! 50 200 -250 -500	μV/°C
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	13 10 - ! 50 200 -250 -500	nA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	10 - 10 - 10 - 10 - 10 - 10 - 10 - 10 -	nA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	50 200 -250 -500	nA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	50 200 -250 -500	nA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	200 -250 -500	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	200 -250 -500	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	-250 -500	pA/°C
$T_{A} = T_{high} \text{ to } T_{low} \text{ (Note 7)} \qquad \qquad - \qquad -50 \qquad -500 \qquad - \qquad -50 \qquad -250 \qquad - \qquad -50$ Average Temperature Coefficient of Input Offset Current $\Delta I_{IO}/\Delta T \qquad - \qquad 10 \qquad - \qquad - \qquad 10 \qquad - \qquad - \qquad 10$	<u> </u>	pA/°C
Current	- 1	pA/°C
$T_A = T_{high}$ to T_{low} (Note 7)		
Input Common Mode Voltage Range (Note 8), V _{ICR} 0 - 28.3 0 - 28.3 0 -	28.3	V
V _{CC} = 30 V, T _A = T _{high} to T _{low} 0 - 28 0 - 28 0 -	28	
Differential Input Voltage Range V_{IDR} V_{CC} V_{CC}	V_{CC}	V
Large Signal Open Loop Voltage Gain A_{VOL}	- '	V/mV
T _A = T _{high} to T _{low} (Note 7)	-	
Channel Separation CS - -120 - - -120 - - -120 1.0 kHz ≤ f ≤ 20 kHz, Input Referenced CS - -120 - - -120 - - -120	-	dB
Common Mode Rejection CMR 50 70 - 50 70 - 50 70 RS \leq 10 k Ω	-	dB
Power Supply Rejection PSR 50 100 - 50 100 - 50 100	_	dB
Output Voltage–High Limit T _A = T _{high} to T _{low} (Note 7)		V
$V_{CC} = 5.0 \text{ V}, R_L = 2.0 \text{ k}\Omega, T_A = 25^{\circ}\text{C}$ 3.3 3.5 - 3.3 3.5 - 3.3 3.5	-	
$V_{CC} = 30 \text{ V}, R_L = 2.0 \text{ k}\Omega$	-	
$V_{CC} = 30 \text{ V}, R_L = 10 \text{ k}\Omega$ 27 28 - 27 28 - 27 28	_	
Output Voltage–Low Limit V_{OL} – 5.0 20 – 5.0 20 – 5.0 V_{OL} – $V_{CC} = 5.0$ V_{C	20	mV
Output Source Current I_{O+} 20 40 - 20 40 - 20 40 V _{ID} = +1.0 V, V_{CC} = 15 V	-	mA
Output Sink Current		
V _{ID} = -1.0 V, V _{CC} = 15 V	-	mA
$V_{ID} = -1.0 \text{ V}, V_{O} = 200 \text{ mV}$ $ -$	-	μΑ
Output Short Circuit to Ground (Note 9)	60	mA
Power Supply Current (Total Device) T _A = T _{high} to T _{low} (Note 7)		mA
$V_{CC} = 30 \text{ V}, V_{O} = 0 \text{ V}, R_{L} = \infty$	3.0	
$V_{CC} = 5 \text{ V}, V_{O} = 0 \text{ V}, R_{L} = \infty$ $- 0.7 1.2 - 0.7 1.2 - 0.7$	1.2	

^{7.} LM258: T_{low} = -25°C, T_{high} = +85°C LM2904/A/E: T_{low} = -40°C, T_{high} = +105°C NCV2904 is qualified for automotive use.

LM358, LM358A, LM358E: T_{low} = 0°C, T_{high} = +70°C LM2904V & NCV2904: T_{low} = -40°C, T_{high} = +125°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{8.} The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of

the common mode voltage range is V_{CC} – 1.7 V.

9. Short circuits from the output to V_{CC} can cause excessive heating and eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.

CIRCUIT DESCRIPTION

The LM358 series is made using two internally compensated, two-stage operational amplifiers. The first stage of each consists of differential input devices Q20 and Q18 with input buffer transistors Q21 and Q17 and the differential to single ended converter Q3 and Q4. The first stage performs not only the first stage gain function but also performs the level shifting and transconductance reduction functions. By reducing the transconductance, a smaller compensation capacitor (only 5.0 pF) can be employed, thus saving chip area. The transconductance reduction is accomplished by splitting the collectors of Q20 and Q18. Another feature of this input stage is that the input common mode range can include the negative supply or ground, in single supply operation, without saturating either the input devices or the differential to single-ended converter. The second stage consists of a standard current source load amplifier stage.

Each amplifier is biased from an internal-voltage regulator which has a low temperature coefficient thus giving each amplifier good temperature characteristics as well as excellent power supply rejection.

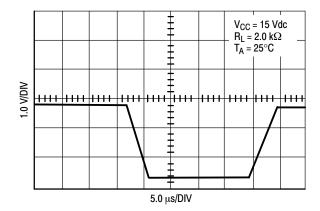


Figure 3. Large Signal Voltage Follower Response

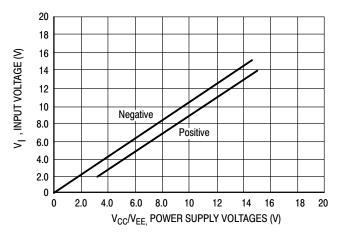


Figure 4. Input Voltage Range

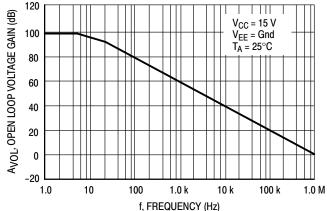


Figure 5. Large-Signal Open Loop Voltage Gain

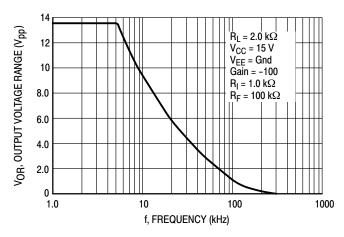


Figure 6. Large-Signal Frequency Response

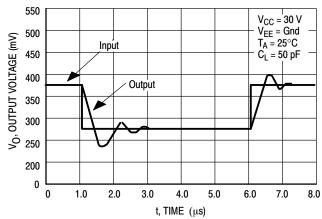


Figure 7. Small Signal Voltage Follower Pulse Response (Noninverting)

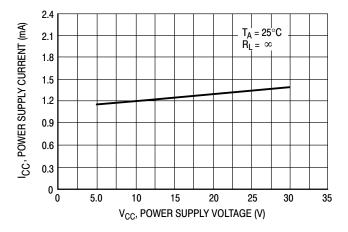


Figure 8. Power Supply Current versus Power Supply Voltage

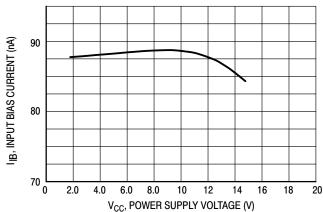


Figure 9. Input Bias Current versus Supply Voltage

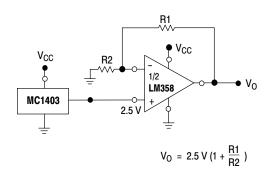


Figure 10. Voltage Reference

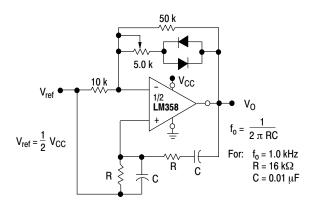


Figure 11. Wien Bridge Oscillator

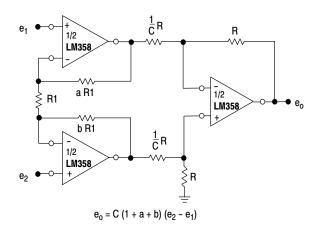


Figure 12. High Impedance Differential Amplifier

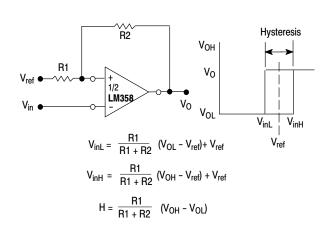


Figure 13. Comparator with Hysteresis

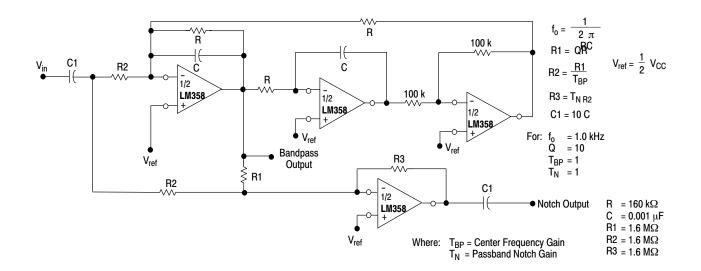
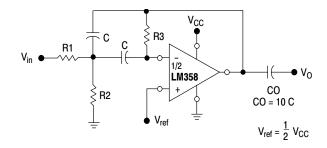


Figure 14. Bi-Quad Filter



Given: f_0 = center frequency $A(f_0)$ = gain at center frequency

Choose value fo, C

Then: R3 =
$$\frac{Q}{\pi f_0 C}$$

R1 = $\frac{R3}{2 A(f_0)}$
R2 = $\frac{R1 R3}{4Q^2 R1 - R3}$

For less than 10% error from operational amplifier. $\frac{Q_0 \, f_0}{BW} < 0.1$

Where fo and BW are expressed in Hz.

If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

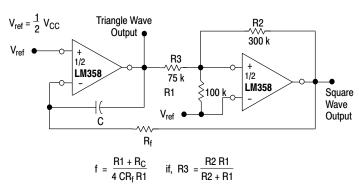


Figure 15. Function Generator

Figure 16. Multiple Feedback Bandpass Filter

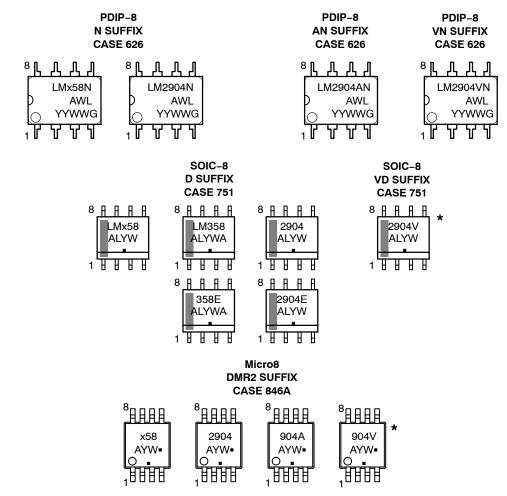
ORDERING INFORMATION

Device	Operating Temperature Range	Package	Shipping [†]
LM358ADR2G			2500 / Tape & Reel
LM358DG		SOIC-8 (Pb-Free)	98 Units / Rail
LM358DR2G		(. 2)	2500 / Tape & Reel
LM358EDR2G	0°C to +70°C	SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM358DMR2G		Micro8 (Pb-Free)	4000 / Tape & Reel
LM358NG		PDIP-8 (Pb-Free)	50 Units / Rail
LM258DG		SOIC-8	98 Units / Rail
LM258DR2G		(Pb-Free)	2500 / Tape & Reel
LM258DMR2G	−25°C to +85°C	Micro8 (Pb-Free)	4000 / Tape & Reel
LM258NG		PDIP-8 (Pb-Free)	50 Units / Rail
LM2904DG		SOIC-8	98 Units / Rail
LM2904DR2G		(Pb-Free)	2500 / Tape & Reel
LM2904EDR2G		SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM2904DMR2G		Micro8 (Pb-Free)	2500 / Tape & Reel
LM2904NG	-40°C to +105°C	PDIP-8 (Pb-Free)	50 Units / Rail
LM2904ADMG		Micro8	4000 / Tape & Reel
LM2904ADMR2G		(Pb-Free)	4000 / Tape & Reel
LM2904ANG		PDIP-8 (Pb-Free)	50 Units / Rail
LM2904VDG		SOIC-8	98 Units / Rail
LM2904VDR2G		(Pb-Free)	2500 / Tape & Reel
LM2904VDMR2G		Micro8 (Pb-Free)	4000 / Tape & Reel
LM2904VNG	-40°C to +125°C	PDIP-8 (Pb-Free)	50 Units / Rail
NCV2904DR2G*		SOIC-8 (Pb-Free)	2500 / Tape & Reel
NCV2904DMR2G*		Micro8 (Pb-Free)	4000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

MARKING DIAGRAMS



x = 2 or 3

A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week G = Pb-Free Package

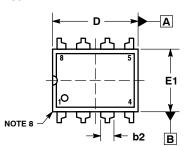
= Pb-Free Package - (Note: Microdot may be in either location)

*This diagram also applies to NCV2904

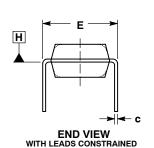


PDIP-8 CASE 626-05 ISSUE P

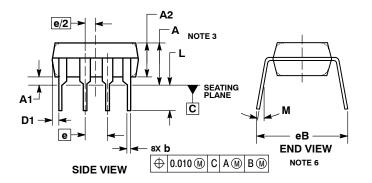
DATE 22 APR 2015



TOP VIEW



NOTE 5



STYLE 1: PIN 1. AC IN 2. DC + IN 3. DC - IN 4. AC IN 5. GROUND 6. OUTPUT

7. AUXILIARY 8. V_{CC}

NOTES

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: INCHES.
 DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACK-
- AGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.
 DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT TO EXCEED 0.10 INCH.
- DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR
- 6. DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE
- DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY.
- 8. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CORNERS).

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α		0.210		5.33
A1	0.015		0.38	
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060	TYP	1.52	TYP
С	0.008	0.014	0.20	0.36
D	0.355	0.400	9.02	10.16
D1	0.005		0.13	
Е	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
е	0.100	BSC	2.54	BSC
eВ		0.430		10.92
L	0.115	0.150	2.92	3.81
M		10°		10°

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code = Assembly Location

WL = Wafer Lot YY = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

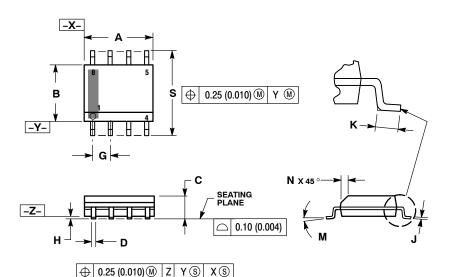
DOCUMENT NUMBER:	98ASB42420B	Electronic versions are uncontrolled except when accessed directly from the Doc Printed versions are uncontrolled except when stamped "CONTROLLED COPY"		
DESCRIPTION:	PDIP-8		PAGE 1 OF 1	

ON Semiconductor and unare trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.



SOIC-8 NB CASE 751-07 **ISSUE AK**

DATE 16 FEB 2011



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.197
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27	1.27 BSC		0 BSC
Н	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
М	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location = Wafer Lot

= Year = Work Week = Pb-Free Package XXXXXX AYWW AYWW H \mathbb{H} Discrete **Discrete** (Pb-Free)

XXXXXX = Specific Device Code = Assembly Location Α

= Year ww = Work Week

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

DOCUMENT NUMBER:	98ASB42564B	Electronic versions are uncontrolled except when accessed directly fror Printed versions are uncontrolled except when stamped "CONTROLLET		
DESCRIPTION:	SOIC-8 NB		PAGE 1 OF 2	

ON Semiconductor and un are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

SOIC-8 NB CASE 751-07 ISSUE AK

DATE 16 FEB 2011

STYLE 1: PIN 1. EMITTER 2. COLLECTOR 3. COLLECTOR 4. EMITTER 5. EMITTER 6. BASE 7. BASE 8. EMITTER	STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 3. COLLECTOR, #2 4. COLLECTOR, #2 5. BASE, #2 6. EMITTER, #2 7. BASE, #1 8. EMITTER, #1	STYLE 3: PIN 1. DRAIN, DIE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. GATE, #2 6. SOURCE, #2 7. GATE, #1 8. SOURCE, #1	
STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN 4. DRAIN 5. GATE 6. GATE 7. SOURCE 8. SOURCE	STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN 4. SOURCE 5. SOURCE 6. GATE 7. GATE 8. SOURCE	STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd	STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #2 7. EMITTER, #1 8. COLLECTOR, #1
STYLE 9: PIN 1. EMITTER, COMMON 2. COLLECTOR, DIE #1 3. COLLECTOR, DIE #2 4. EMITTER, COMMON 5. EMITTER, COMMON 6. BASE, DIE #2 7. BASE, DIE #1 8. EMITTER, COMMON	STYLE 10: PIN 1. GROUND 2. BIAS 1 3. OUTPUT 4. GROUND 5. GROUND 6. BIAS 2 7. INPUT 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE	STYLE 11: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 8. DRAIN 1	STYLE 12: PIN 1. SOURCE 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
STYLE 13: PIN 1. N.C. 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN	STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE 4. P-GATE 5. P-DRAIN 6. P-DRAIN 7. N-DRAIN 8. N-DRAIN	8. DHAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 3. ANODE 1 4. ANODE 1 5. CATHODE, COMMON 6. CATHODE, COMMON 7. CATHODE, COMMON 8. CATHODE, COMMON	STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2 4. BASE, DIE #2 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 7. COLLECTOR, DIE #1 8. COLLECTOR, DIE #1
STYLE 17: PIN 1. VCC 2. V2OUT 3. V1OUT 4. TXE 5. RXE 6. VEE 7. GND 8. ACC	STYLE 18: PIN 1. ANODE 2. ANODE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. CATHODE 8. CATHODE	STYLE 19: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1	STYLE 20: PIN 1. SOURCE (N) 2. GATE (N) 3. SOURCE (P) 4. GATE (P) 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
6. VEE 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3. CATHODE 3 4. CATHODE 4 5. CATHODE 5 6. COMMON ANODE 7. COMMON ANODE 8. CATHODE 6	STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3. COMMON CATHODE/VCC 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND	STYLE 23: PIN 1. LINE 1 IN 2. COMMON ANODE/GND 3. COMMON ANODE/GND 4. LINE 2 IN 5. LINE 2 OUT 6. COMMON ANODE/GND 7. COMMON ANODE/GND 8. LINE 1 OUT	0 COLLECTOR/ANODE
STYLE 25: PIN 1. VIN 2. N/C 3. REXT 4. GND 5. IOUT 6. IOUT 7. IOUT 8. IOUT	STYLE 26: PIN 1. GND 2. dv/dt 3. ENABLE 4. ILIMIT 5. SOURCE 6. SOURCE 7. SOURCE 8. VCC	STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN	STYLE 28: PIN 1. SW_TO_GND 2. DASIC_OFF 3. DASIC_SW_DET 4. GND 5. V_MON 6. VBULK 7. VBULK 8. VIN
STYLE 29: PIN 1. BASE, DIE #1 2. EMITTER, #1 3. BASE, #2 4. EMITTER, #2 5. COLLECTOR, #2 6. COLLECTOR, #2 7. COLLECTOR, #1 8. COLLECTOR, #1	STYLE 30: PIN 1. DRAIN 1 2. DRAIN 1 3. GATE 2 4. SOURCE 2 5. SOURCE 1/DRAIN 2 6. SOURCE 1/DRAIN 2 7. SOURCE 1/DRAIN 2 8. GATE 1		

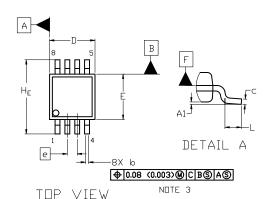
DOCUMENT NUMBER:	: 98ASB42564B Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in		' '
DESCRIPTION:	SOIC-8 NB		PAGE 2 OF 2

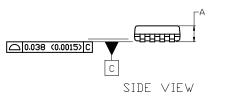
ON Semiconductor and IN are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.



Micro8 CASE 846A-02 ISSUE K

DATE 16 JUL 2020

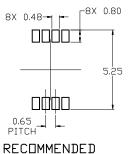






NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.10 mm IN EXCESS OF MAXIMUM MATERIAL CONDITION.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. DIMENSION E DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 mm PER SIDE. DIMENSIONS D AND E ARE DETERMINED AT DATUM F.
- 5. DATUMS A AND B ARE TO BE DETERMINED AT DATUM F.
- 6. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.



MOUNTING FOOTPRINT

DIM	MILLIMETERS			
ויונע	MIN.	N□M.	MAX.	
Α			1.10	
A1	0.05	0.08	0.15	
b	0.25	0.33	0.40	
С	0.13	0.18	0.23	
D	2.90	3.00	3.10	
E	2.90	3.00	3.10	
е	0.65 BSC			
HE	4.75	4.90	5.05	
L	0.40	0.55	0.70	

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code A = Assembly Location

Y = Year W = Work Week • = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:	STYLE 2:	STYLE 3:
PIN 1. SOURCE	PIN 1. SOURCE 1	PIN 1. N-SOURCE
SOURCE	2. GATE 1	2. N-GATE
SOURCE	SOURCE 2	P-SOURCE
GATE	4. GATE 2	4. P-GATE
DRAIN	5. DRAIN 2	5. P-DRAIN
DRAIN	6. DRAIN 2	6. P-DRAIN
7. DRAIN	7. DRAIN 1	7. N-DRAIN
8. DRAIN	8. DRAIN 1	8. N-DRAIN

DOCUMENT NUMBER:	98ASB14087C	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	MICRO8		PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and the are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and see no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Operational Amplifiers - Op Amps category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below:

OPA2991IDSGR OPA607IDCKT 007614D 633773R 635798C 635801A 702115D 709228FB 741528D NCV33072ADR2G

SC2903VDR2G LM258AYDT LM358SNG 430227FB 430228DB 460932C AZV831KTR-G1 409256CB 430232AB LM2904DR2GH

LM358YDT LT1678IS8 042225DB 058184EB 070530X SC2902DG 714228XB 714846BB 873836HB MIC918YC5-TR TS912BIYDT

NCS2004MUTAG NCV33202DMR2G M38510/13101BPA NTE925 SC2904DR2G SC358DR2G LM358EDR2G AP4310AUMTR-AG1

HA1630D02MMEL-E NJM358CG-TE2 HA1630S01LPEL-E LM324AWPT HA1630Q06TELL-E NJM4558CG-TE2 AZV358MMTR-G1

SCY33178DR2G NCS4325DR2G LM7301SN1T1G NJU77806F3-TE1